# XC7SH04 Inverter

Rev. 01 — 1 September 2009

**Product data sheet** 

#### 1. **General description**

XC7SH04 is a high-speed Si-gate CMOS device. It provides an inverting buffer.

#### 2. **Features**

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options
- ESD protection:
  - ◆ HBM JESD22-A114E: exceeds 2000 V
  - ◆ MM JESD22-A115-A: exceeds 200 V
  - ◆ CDM JESD22-C101C: exceeds 1000 V
- Specified from –40 °C to +125 °C

#### **Ordering information** 3.

Table 1. **Ordering information** 

Type number	Package	Package						
	Temperature range	Name	Description	Version				
XC7SH04GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
XC7SH04GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				



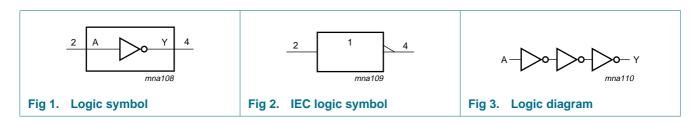
## 4. Marking

#### Table 2. Marking codes

Type number	Marking <sup>[1]</sup>
XC7SH04GW	fC
XC7SH04GV	f04

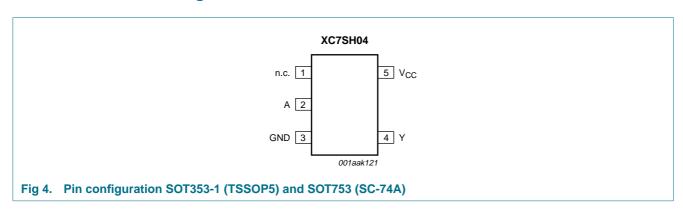
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
n.c.	1	not connected
Α	2	data input
GND	3	ground (0 V)
Υ	4	data output
$V_{CC}$	5	supply voltage

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## 7. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level

Input	Output
Α	Υ
L	Н
Н	L

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
$V_{I}$	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V}$	-20	-	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I <sub>O</sub>	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	75	mA
$I_{\text{GND}}$	ground current		<b>-75</b>	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C	[2] _	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For both TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

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## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		2.0	5.0	5.5	V
$V_{I}$	input voltage		0	-	5.5	V
Vo	output voltage		0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	-	-	100	ns/V
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	ns/V

## 10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = -50 \mu A$ ; $V_{CC} = 2.0 \text{ V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -50 \mu\text{A};  V_{CC} = 3.0 \text{V}$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O = -50 \mu A$ ; $V_{CC} = 4.5 \text{ V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 50 \mu A$ ; $V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 3.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A$ ; $V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$ ; $V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
Cı	input capacitance		-	1.5	10	-	10	-	10	pF

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## 11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V. For test circuit see Figure 6.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
$t_{pd}$	propagation	A to Y; see Figure 5	<u>[1]</u>								
	delay	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]								
		C <sub>L</sub> = 15 pF		-	4.3	7.1	1.0	8.5	1.0	11.0	ns
		$C_L = 50 pF$		-	6.1	10.6	1.0	12	1.0	14.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[3]</u>								
		C <sub>L</sub> = 15 pF		-	3.1	5.5	1.0	6.5	1.0	7.0	ns
		$C_L = 50 pF$		-	4.5	7.5	1.0	8.5	1.0	9.5	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}$ ; $f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	15	-	-	-	-	-	pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

<sup>[2]</sup> Typical values are measured at  $V_{CC}$  = 3.3 V.

<sup>[3]</sup> Typical values are measured at  $V_{CC} = 5.0 \text{ V}$ .

## 12. Waveforms

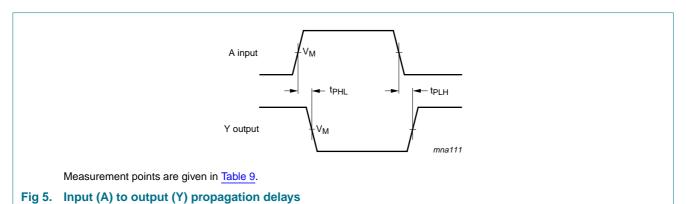
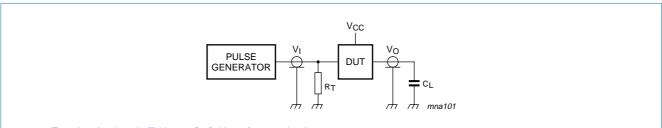


Table 9. Measurement point

Туре	Input	Input	Output
	V <sub>I</sub>	V <sub>M</sub>	V <sub>M</sub>
XC7SH04	GND to V <sub>CC</sub>	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$



Test data is given in Table 10. Definitions for test circuit:

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 6. Load circuitry for switching times

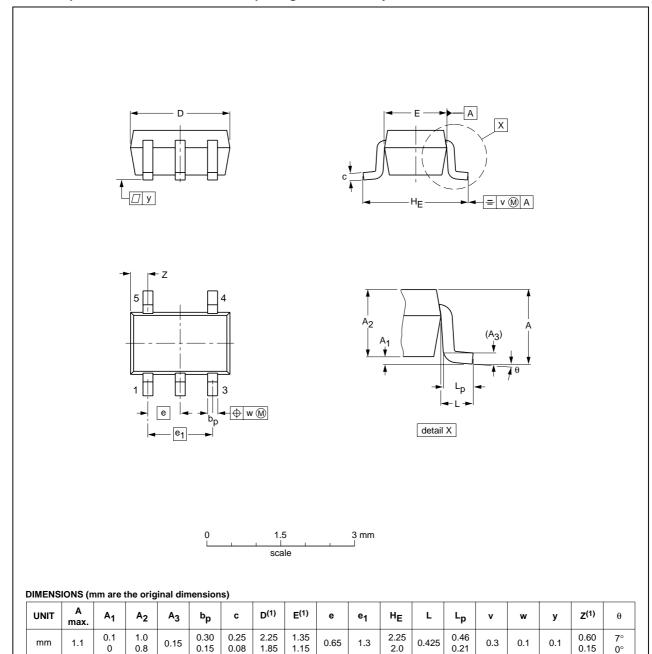
Table 10. Test data

Туре	Input	Input I		Test
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	
XC7SH04	V <sub>CC</sub>	≤ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

## 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	TLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT353-1		MO-203	SC-88A			<del>00-09-01</del> 03-02-19	

Fig 7. Package outline SOT353-1 (TSSOP5)

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### Plastic surface-mounted package; 5 leads

SOT753

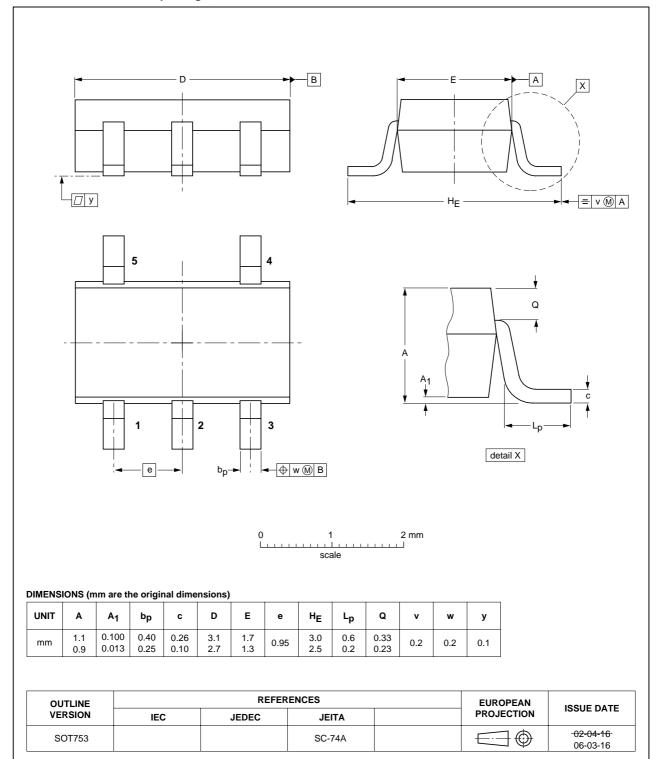


Fig 8. Package outline SOT753 (SC-74A)

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## 14. Abbreviations

### Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 15. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
XC7SH04_1	20090901	Product data sheet	-	-

## 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions"
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